#### CEDM7001VL

SURFACE MOUNT SILICON **N-CHANNEL ENHANCEMENT-MODE** MOSFET



# **APPLICATIO**

- Load/Power
- DC-DC converters
- · Battery powered portable equipment

	FEATURES:
	<ul> <li>100mW Power Dissipation</li> </ul>
	<ul> <li>0.32mm very low package</li> </ul>
DNS:	<ul> <li>Low rDS(ON)</li> </ul>
r switches	<ul> <li>Low threshold voltage</li> </ul>
verters	• Logic level compatible

MAXIMUM RATINGS: (T <sub>A</sub> =25°C)	SYMBOL		UNITS
Drain-Source Voltage	V <sub>DS</sub>	20	V
Gate-Source Voltage	V <sub>GS</sub>	10	V
Continuous Drain Current (Steady State)	۱ <sub>D</sub>	100	mA
Peak Drain Current, tp=10µs	<sup>I</sup> DM	200	mA
Power Dissipation	PD	100	mW
Operating and Storage Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

#### **ELECTRICAL CHARACTERISTICS:** ( $T_A$ =25°C unless otherwise noted) SYMBOL **TEST CONDITIONS** MIN TYP MAX UNITS IGSSF, IGSSR VGS=10V, VDS=0 1.0 μA V<sub>DS</sub>=20V, V<sub>GS</sub>=0 1.0 μA IDSS **BV**DSS V<sub>GS</sub>=0, I<sub>D</sub>=100µA 20 V V<sub>DS</sub>=V<sub>GS</sub>, I<sub>D</sub>=250µA 0.6 0.9 V VGS(th) 3.0 V<sub>GS</sub>=4.0V, I<sub>D</sub>=10mA 0.9 Ω rDS(ON) V<sub>GS</sub>=2.5V, I<sub>D</sub>=10mA 1.3 4.0 Ω rDS(ON) V<sub>GS</sub>=1.5V, I<sub>D</sub>=1.0mA 15 Ω rDS(ON) V<sub>DS</sub>=10V, I<sub>D</sub>=100mA 100 mS <sup>g</sup>FS V<sub>DS</sub>=3.0V, V<sub>GS</sub>=0, f=1.0MHz 4.0 pF Crss V<sub>DS</sub>=3.0V, V<sub>GS</sub>=0, f=1.0MHz 9.0 pF Ciss $\mathbf{C}_{\mathrm{OSS}}$ V<sub>DS</sub>=3.0V, V<sub>GS</sub>=0, f=1.0MHz 9.5 pF Qg(tot) V<sub>DS</sub>=10V, V<sub>GS</sub>=4.5V, I<sub>D</sub>=100mA 0.566 nC $\mathsf{Q}_{\mathsf{gs}}$ V<sub>DS</sub>=10V, V<sub>GS</sub>=4.5V, I<sub>D</sub>=100mA 0.16 nC 0.08 nC Q<sub>gd</sub> V<sub>DS</sub>=10V, V<sub>GS</sub>=4.5V, I<sub>D</sub>=100mA V<sub>DD</sub>=3.0V, V<sub>GS</sub>=2.5V, I<sub>D</sub>=10mA 50 ns ton 75 V<sub>DD</sub>=3.0V, V<sub>GS</sub>=2.5V, I<sub>D</sub>=10mA ns toff

# Semiconductor Co

www.centralsemi.com

## **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CEDM7001VL is an N-Channel Enhancement-mode MOSFET packaged in the very low profile SOT-883VL case. The device is designed for space constrained high speed amplifier and driver applications where package height is a critical design element. This MOSFET offers low rDS(ON) and low gate charge.

#### **MARKING CODE: 7**

#### COMPLEMENTARY P-CHANNEL: CEDM8001VL

- profile
- Logic level compatible

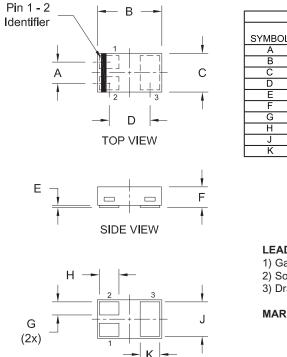
· Small leadless surface mount package

R2 (9-September 2014)





#### SURFACE MOUNT SILICON N-CHANNEL **ENHANCEMENT-MODE** MOSFET



#### SOT-883VL CASE - MECHANICAL OUTLINE

LEAD CODE:

DIMENSIONS

MILLIMETERS

0.95

0.55

0.00

0.30

0.10

0.20

0.45

0.20

SOT-883VL (REV:R0)

MIN MAX

0.35

0.65

1.05

0.65

0.05

0.32

0.20

0.30

0.30

INCHES

MIN MAX

0.014

0.037 0.041

0.022 0.026

0.000 0.002

0.012 0.013

0.004 0.008

0.018 0.022

0.008 0.012

0.012

0.008

1) Gate 2) Source 3) Drain

MARKING CODE: 7

Package Type Options (all dimensions are maximum - in mm)

BOTTOM VIEW

Package	Length	Width	Height	P <sub>D</sub> (mW)	Central Item Number
SOT-883VL	1.05	0.65	0.32	100	CEDM7001VL
SOT-883L	1.05	0.65	0.40	100	CEDM7001
SOT-953	1.05	1.05	0.50	250	CMNDM7001
SOT-523	1.70	1.70	0.78	250	CMUDM7001

R0

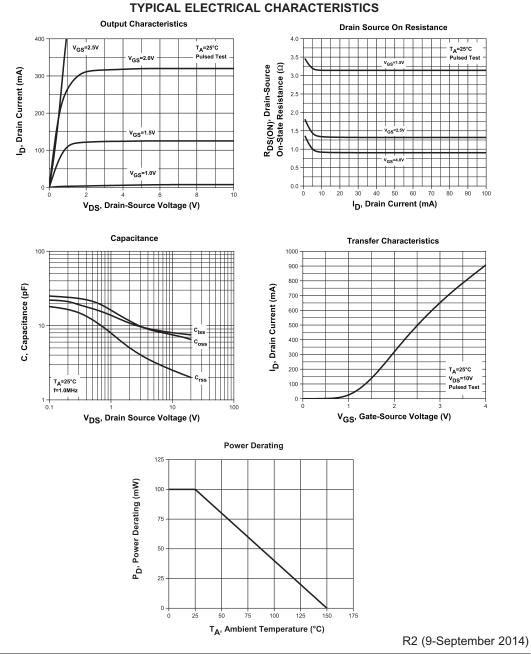
R2 (9-September 2014)

www.centralsemi.com





#### SURFACE MOUNT SILICON **N-CHANNEL** ENHANCEMENT-MODE MOSFET



www.centralsemi.com

#### CEDM7001VL



SURFACE MOUNT SILICON N-CHANNEL ENHANCEMENT-MODE MOSFET

### SERVICES

- · Bonded Inventory
- Custom Electrical Screening
- Custom Electrical Characteristic Curves
- SPICE Models
- Custom Packaging
- Package Base Options
- Custom Device Development/Multi Discrete Modules (MDM<sup>™</sup>)
- Bare Die for Hybrid Applications

LIMITATIONS AND DAMAGES DISCLAIMER: In no event shall Central be liable for any collateral, indirect, punitive, incidental, consequential, or exemplary damages in connection with or arising out of a purchase order or contract or the use of products provided hereunder, regardless of whether Central has been advised of the possibility of such damages. Excluded damages shall include, but not be restricted to: cost of removal or reinstallation, rework, ancillary costs to the procurement of substitute products, loss of profits, loss of savings, loss of use, loss of data, or business interruption. No claim, suit, or action shall be brought against Central more than two (2) years after the related cause of action has occurred.

In no event shall Central's aggregate liability from any warranty, indemnity, or other obligation arising out of or in connection with a purchase order or contract, or any use of any Central product provided hereunder, exceed the total amount paid to Central for the specific products sold under a purchase order or contract with respect to which losses or damages are claimed. The existence of more than one (1) claim against the specific products sold to Buyer under a purchase order or contract shall not enlarge or extend this limit.

Buyer understands and agrees that the foregoing liability limitations are essential elements of a purchase order or contract and that in the absence of such limitations, the material and economic terms of the purchase order or contract would be substantially different.

R2 (9-September 2014)

www.centralsemi.com